

Ca²⁺-Doped CeBr₃ Scintillating Material

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INTRODUCTION

This paper presents on the scintillation properties of CeBr₃ crystals grown with the divalent dopant Ca²⁺. CeBr₃ is a self-activated lanthanide scintillator, which has received considerable attention [1]. due to proportionality and energy resolution. Because the material possesses no intrinsic radioactivity, CeBr₃ has a high potential to outperform scintillators such as cerium-activated lanthanum tribromide or lanthanum-based elpasolites [2], making it an excellent candidate for gamma spectrometers for passive detection and identification of special nuclear material [3,4]. Unfortunately, fracture during synthesis complicates the growth of CeBr₃ crystals in sizes large enough to usefully to identify radioisotopes quickly.

Electronic valence effects exert a powerful influence on material and optical properties. Aliovalent substitution may strengthen the material without significantly degrading the scintillating properties (Harrison 2010). Aliovalently calcium-doped cerium tribromide (CeBr₃:Ca²⁺) crystals were prepared according to careful theoretical modeling and delivered to the Remote Sensing Laboratory (RSL) for assessment and evaluation (Fig. 1). The reliability of large crystals may be questionable and their manufacturing yield may be low, as these hexagonal crystals may fracture easily [5,6]. However, increasing the fracture toughness of the crystals may lead to significant gains in the practical scale for CeBr₃ scintillators [7]. To that end, we explored exploiting elastic interaction with dislocations, which may result an increase in hardening rate [8].



Fig. 1. Packaged scintillator of 0.2 atomic% Ca²⁺-doped CeBr₃.

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BACKGROUND

We seek to achieve ultralow activity and high strength cerium bromide (CeBr₃) scintillators. This work pursued developing low cost, high-resolution γ -ray scintillators based on new fracture resistant alloys of CeBr₃. Because CeBr₃ already exhibits superior scintillation characteristics [9,10], the alloying element(s) used to strengthen the crystal must not degrade the scintillation properties. Aliovalent alloying provides more strengthening than isovalent alloying. The solid solution strengthening τ based on lattice distortions due to some small concentration of dopant approximately is

$$\tau = \gamma \cdot Gc^{\frac{1}{2}}, \quad (1)$$

where G is the shear modulus, c is the concentration of solute in atomic fraction, and γ is a proportionality constant [11,12]. For spherically symmetric distortions, such as those found in isovalent alloying, γ typically takes on values that are significantly smaller than unity, from 10^{-4} to 10^{-6} . For tetragonal lattice distortions, such as those created from solute atoms of a different valence, γ can be nearly unity. Therefore, aliovalent alloying is more effective for a given concentration of solute [12].

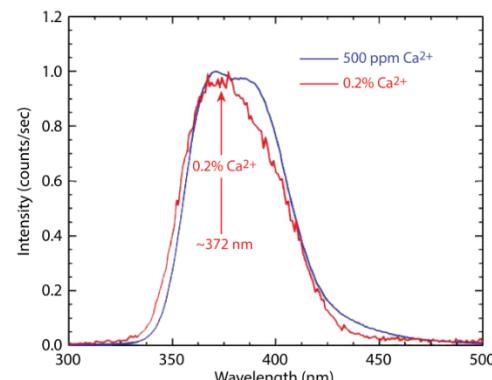


Fig. 2. Emission spectrum measured with 6 × 2 mm 0.2 atomic% Ca²⁺-doped CeBr₃ crystal in the permanent

canister compared to a similar measurement for a 500 ppm Ca^{2+} -doped CeBr_3 crystal.

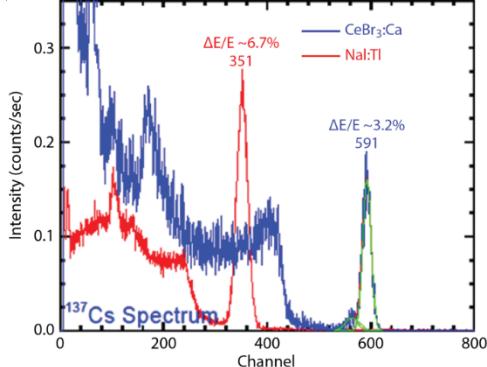


Fig. 3. Light output measurement relative to NaI:Tl indicates 62,000 photons per MeV for Ca^{2+} -doped CeBr_3 crystal. Green curve represents a Gaussian fit to the data acquired with the $\text{CeBr}_3:\text{Ca}^{2+}$ crystal.

For this study, Dynasil Radiation Monitoring Devices, Inc. (RMD) grew small diameter (up to ~ 1 cm) single crystals of CeBr_3 doped with Ca^{2+} . RSL assessed the RMD crystal. RSL acquired spectra with different isotopes using the RMD crystal using the techniques described by Guss [7,13]. Fig. 2 presents the emission spectrum for this crystallite. These results are consistent with recent findings [14]. The increase in doping level led to a slight blue shift in the emission spectrum. Fig. 3 shows a light output measurement for the crystallite estimated at 62,000 photons per MeV based on comparison to the thallium-doped sodium iodide (NaI:Tl) light yield.

METHODS

Maintaining proportionality is key to producing a strong, high-performance scintillator. Measurements for relative light yield proportionality for both doped and undoped samples of CeBr_3 ensured no loss in performance resulted by aliovalently doping the crystal. The light output and proportionality, however, appear to be like CeBr_3 . There was a reduced yield at low energy. Relative light yield proportionality measurements suggest that dopants do not significantly affect proportionality at higher energies. Fig. 4 presents a plot of light yield proportionality for a doped sample.

RSL completed additional testing and evaluation of the new crystal as well as the assessment of benchmarking spectroscopy data. Fig. 5 shows a typical spectroscopy result using a ^{137}Cs radiation source for our crystallites. We obtained an energy resolution of 4.5% at 661 keV gamma ray energy for the packaged crystallite. Spectra obtained for ^{241}Am , ^{60}Co , ^{228}Th , and background further exemplified $\text{CeBr}_3:\text{Ca}^{2+}$ performance over a broader energy range. The radiation source spectra measurements represented a data

acquisition for 3600 seconds with the radiation source in contact with the crystal face using typical source strengths of several μCi . The laboratory background acquisition time was 3×10^5 sec.

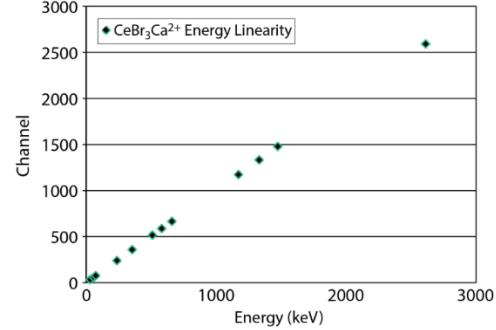


Fig. 4. Relative light yield proportionality of 0.2 atomic% Ca^{2+} -doped CeBr_3 .

We have observed Ca^{2+} to be a most promising dopant, since it significantly reduces the nonproportionality and improves the energy resolution of pure CeBr_3 . We have measured the nonproportionality in the energy range from 32 keV up to 1274 keV. At 32 keV, the $\text{CeBr}_3:\text{Ca}^{2+}$ deviates about 4% from the ideal case (10% for pure CeBr_3). We achieved an excellent energy resolution of 3.2% at 662 keV and light output of $\sim 62,000$ photons/MeV [15,16].

Aliovalent substitution, in which an ion of different valence (e.g., Ca^{2+} for Ce^{3+} in CeBr_3) replaces a host ion is a more potent method of strengthening than isovalent substitution (i.e., replacing a fraction of ions with like-valence ions). In this approach, the formation of intrinsic defects necessary to maintain charge neutrality results in complexes with long-range interactions in the crystal. However, due to its hexagonal crystal structure (UCl_3), pure CeBr_3 can fracture during crystal growth, detector fabrication, and subsequent use under field conditions, thus impacting manufacturing yield and reliability for large crystals [6].

The elastic interaction (tetragonal distortion) with dislocations may result in an increase in hardening rate [8]. Concentration levels necessary to increase the yield strength by an order of magnitude may be in the 100–500 ppm range (0.01%–0.05%) for aliovalent substitution, whereas isovalent substitution may require 10%–50% to achieve the same effect.

For these reasons, aliovalent substitution may improve the strength of CeBr_3 . SNL demonstrated success with this approach, achieving a dramatic reduction of fracture in aliovalent alloys compared with pure CeBr_3 crystals [12]. Prototype high-purity CeBr_3 ingots compounded with the addition of 2% of CaBr_2 added provided the charge in a closed ampoule before melting and solidification in a gradient-freeze process. Pure CeBr_3 ingots solidified under these conditions were severely fractured, yielding only centimeter-sized shards. The lesson learned was that 2% was

too high of a charge for the calcium. We performed mass analysis of the material and recalculated the DFT with a lower charge of calcium. We performed an assessment of the spectroscopic performance of $\text{CeBr}_3:\text{Ca}$ shards.

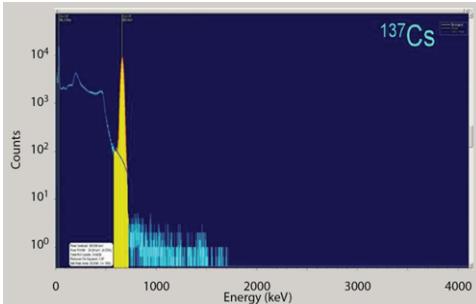


Fig. 5. ^{137}Cs spectrum with 1.9% Ca^{2+} -doped CeBr_3 in the permanent canister.

RESULTS

RMD grew, packaged, and delivered to RSL the 2% calcium-doped $\text{CeBr}_3:\text{Ca}$ crystallite. RMD assessed crystal growth strategies for performing growth with lower concentrations of calcium. Several minor tasks remained to complete characterization of the calcium-doped crystal. RSL assessed the spectroscopic performance of the crystal. RSL acquired spectra with different isotopes using the RMD crystal using the techniques described by Guss [7,17,18]. Fig. 2 shows the emission spectrum for this crystallite. Fig. 3 shows a light output measurement for the crystallite estimated at 62,000 photons per MeV based on light yield.

The packaging of the crystallite impacted the performance of $\text{CeBr}_3:\text{Ca}^{2+}$, due to the gamma-ray interactions with the added material, including scattering, and energy-absorption. Figs. 3 presents the ^{137}Cs radiation source spectrum. A slight degradation in performance is associated with the permanent package of the crystal.

Sandia National Laboratories (SNL) performed density functional theory (DFT) model calculations for a nominal doping (i.e., 2%) of calcium in CeBr_3 . They also performed DFT model calculations with less dilute doping of calcium in CeBr_3 . This helped assess what doping concentration would lead to changes in optical and mechanical properties.

SNL measured the calcium concentration by the inductively coupled plasma mass spectrometry. SNL performed microhardness measurements to see if the aliovalent approach hardened the crystal as expected. SNL measured the microhardness (Vickers hardness [19]) and indentation toughness of these samples. Due to the size limitation, we could not obtain enough statistics and confidence on these measured values. Therefore, we do not report the results here. Future work should include studies in correlation between sheer strength and Ca^{2+} concentration.

CALCIUM CONCENTRATION

We have measured the calcium concentration in the CeBr_3 by the inductively coupled plasma mass spectrometry (ICP-MS) technique from the crystals prepared by RMD. ICP-MS is a type of mass spectrometry capable of detecting metals and several non-metals at concentrations as low as one part in 10^{12} (part per trillion). SNL performed the ICP-MS. SNL analyzed the concentration of calcium in the crystals. We used the average calcium weight % concentration, $x = 0.000214$, in our complex of $\text{Ce}_{(1-x)}\text{Ca}_x\text{Br}_{(3-x)}$, to evaluate the formula for atomic percentage:

$$\text{Atomic \%} = 40.078x/[140.116(1-x) + 40.078x + 79.904(3-x)] = 0.00228 = 0.228\% \quad (2)$$

Based on our measurements, using three different samples (~0.2 grams), we have three consistent data sets indicating that the calcium concentration in these crystals is 0.0214 ± 0.0102 wt.% (one σ) by weight, which corresponds to an atom percentage of 0.228 at.%.

Results plotted in Fig. 6 indicate the approximate solidus, liquidus, and eutectic lines. Not plotted are some additional data taken at 20% and 30%, which indicate the liquidus continues the near-linear trend. Note that our current experimental upper bound for the solid solubility is the data point at 2.35%, which must lie well within the $\alpha + \beta$ field, with the detection of the eutectic temperature T_e . This concentration is considerably less than the intersection of the extrapolated solidus and the eutectic temperature; therefore, the solidus line is clearly nonlinear and probably exhibits retrograde solubility well below the melting point of pure CeBr_3 , as observed for sparingly soluble impurities in other systems. This behavior characterizes a variation of the segregation coefficient with temperature, as analyzed by Hall [20]. For example, the maximum solid solubility for sparingly soluble impurities in silicon and germanium follow a simple empirical correlation with k_0 , the limiting equilibrium segregation coefficient, as C_L approaches 0: $C_{S,\max} = k_0/10$ [21]. Based on this relation, the solidus extrapolates to $k_{\text{eff}}/10 = 1.1\%$ at the eutectic temperature to estimate the minimum extent of the eutectic line towards the CeBr_3 side of the phase diagram (Fig. 6).

The eutectic composition extrapolated from the points plotted is near 37% calcium; however, the nominal 20% and 30% data indicate it could be near 50%. Future experimentation will better accurately determine both the eutectic composition and the β phase, which in fact could turn out to be a ternary such as CaCeBr_5 or Ca_2CeBr_7 .

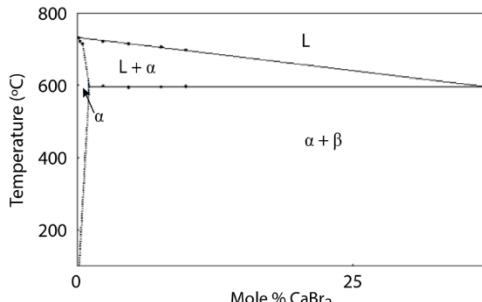


Fig. 6. Phase diagram for $\text{CeBr}_3\text{-CaBr}_2$.
SUMMARY

To summarize, new DFT simulations demonstrate a capability for predicting properties of doped CeBr_3 materials that is unavailable elsewhere but is critical to study the property-limiting valence phenomena in ionic compounds. During this project, we assessed concentrations and the solubility limit. RSL benchmarked the Ca^{2+} -doped CeBr_3 crystal. The Ca^{2+} -doped CeBr_3 crystal has improved energy resolution (i.e., 3.2%) and linearity over the pure CeBr_3 crystal.

Based on the recent literature on strengthening mechanisms [22], there are compelling requirements to research and several ideas, questions, and answers to share. Sinha's paper on aliovalent strengthening of CaF_2 attempts to determine mechanisms for low and high temperatures. Sinha and Nicholson [22] found that Y(III) gave an order of magnitude greater increase in critical resolve shear stress than Na(I). They conclude the long-range retarding force on dislocations at high temperature is likely due to the induced reorientation of Na(I)/F-vacancy or Y(III)/F-interstitial dipoles in the stress fields of moving dislocations (Snoek effect). This suggested role of the Snoek effect [23] is in accord with analysis of the athermal regime in recent papers on Y stabilized zirconia and other materials [9,17,24-30].

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